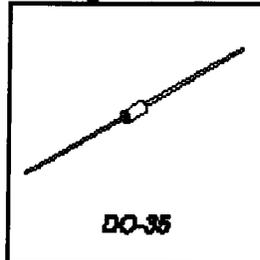


1N4829

Stabistor Diode

Package



PACKAGE DIMENSIONS

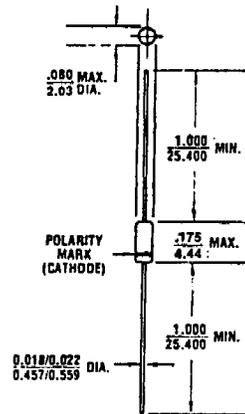


FIGURE 1

All dimensions in $\frac{\text{INCH}}{\text{m.m.}}$

DO-35

MECHANICAL CHARACTERISTICS

*Case: Hermetically sealed glass DO-35. DO-7 and DO-41 glass are optional. Single p-n junction devices also offered in DO-41 plastic.

Finish: All external surfaces are corrosion resistant and leads solderable.

Thermal Resistance: 200° C/W typical for DO-35 at 0.375 inches from body.

Mounting Position: Any.

Polarity: Cathode marked with band. To be operated with cathode negative for normal low voltage operation.

* Designate case size when ordering.

Absolute Maximum Ratings	Symbol	Max	Unit
Power Dissipation	Power	0.5	W
Reverse Voltage	V_R	20	V

Electrical Characteristics	Symbol	Min	Typ	Max	Unit
Forward Voltage ($I_F=10 \text{ mA}$)	V_F			1.61	V
Reverse Leakage Current ($T_A=25^\circ\text{C}$, $V_R=20 \text{ V}$)	I_R			0.1	μA
Reverse Breakdown Voltage ($I_{BR}=5 \mu\text{A}$)	V_{BR}	30			V
Output Capacitance ($V_R=0 \text{ V}$)	C_o			25	pF



Quality Semi-Conductors